



#### **NPN SMALL SIGNAL TRANSISTOR IN SOT23**

### **Features**

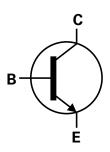
- Ideally Suited for Automatic Insertion
- Complementary PNP Types: BC856–BC858
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An automotive-compliant part is available under separate datasheet (<u>BC846AQ-BC848CQ</u>)

## **Mechanical Data**

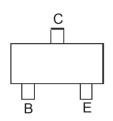
- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)







Device Symbol



Top View Pin-Out

### **Ordering Information** (Note 4)

Dant Namehan	DI	Mandaha a	Dool Cine (inches)	Packing		
Part Number	Package	Marking	Reel Size (inches)	Qty.	Carrier	
BC846A-7-F	SOT23	K1Q	7	3,000	Reel	
BC846B-7-F	SOT23	K1R	7	3,000	Reel	
BC846B-13-F	SOT23	K1R	13	10,000	Reel	
BC847A-7-F	SOT23	K1Q	7	3,000	Reel	
BC847A-13-F	SOT23	K1Q	13	10,000	Reel	
BC847B-7-F	SOT23	K1R	7	3,000	Reel	
BC847B-13-F	SOT23	K1R	13	10,000	Reel	
BC847C-7-F	SOT23	K1M	7	3,000	Reel	
BC847C-13-F	SOT23	K1M	13	10,000	Reel	
BC848A-7-F	SOT23	K1Q	7	3,000	Reel	
BC848B-7-F	SOT23	K1R	7	3,000	Reel	
BC848B-13-F	SOT23	K1R	13	10,000	Reel	
BC848C-7-F	SOT23	K1M	7	3,000	Reel	

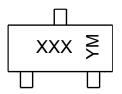
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

May 2024



# **Marking Information**



XXX = Product Type Marking Code YM = Date Code Marking Y or  $\overline{\underline{Y}}$  = Year (ex: L = 2024) M or  $\overline{\underline{M}}$  = Month (ex: 9 = September)

#### Date Code Key

Year	2007	-	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	U	-	L	М	N	Р	R	S	Т	U	V	W
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

# **Absolute Maximum Ratings** (@TA = +25°C, unless otherwise specified.)

Characteristi	С	Symbol	Value	Unit
	BC846A/B		80	
Collector-Base Voltage	BC847A/B/C	Vсво	50	V
	BC848A/B/C		30	
	BC846A/B		65	
Collector-Emitter Voltage	BC847A/B/C	VCEO	45	V
	BC848A/B/C		30	
Emitter-Base Voltage	BC846A/B BC847A/B/C	VEBO	6.0	V
	BC848A/B/C		5.0	
Continuous Collector Current		Ic	100	mA
Peak Collector Current		Ісм	200	mA
Peak Emitter Current		ІЕМ	200	mA

### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Dower Discipation	(Note 5)	D-	310	mW	
Power Dissipation	(Note 6)	PD	350		
The moral Designation to Ambient	(Note 5)	Б	403	90/14/	
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>θJA</sub>	357	°C/W	
Thermal Resistance, Junction to Leads (Note 7)		Røjl	350	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-65 to +150	°C	

### ESD Ratings (Note 8)

Notes:

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions

whilst operating in a steady-state.

<sup>6.</sup> Same as Note 5, except the device is mounted on 15mm x 15mm 1oz copper. 7. Thermal resistance from junction to solder-point (at the end of the leads).
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**

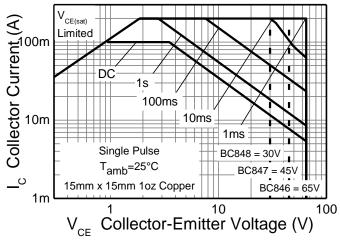


Figure 1. Safe Operating Area

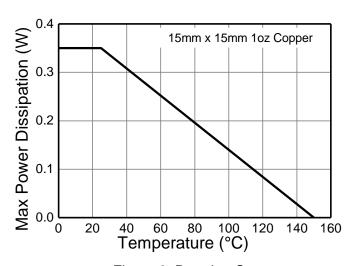


Figure 2. Derating Curve

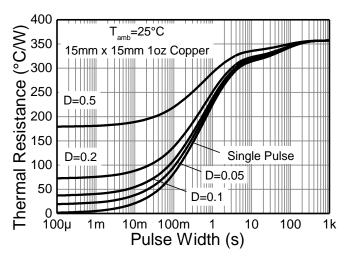


Figure 3. Transient Thermal Impedance

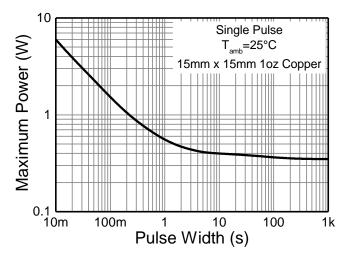


Figure 4. Pulse Power Dissipation



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Charac	teristic		Symbol	Min	Тур	Max	Unit	Test Condition	
		BC846A/B		80	- 71				
Collector-Base Breakdown Voltage BC847A/B/C BC848A/B/C		BC847A/B/C	ВУсво	50	_	_	V	Ic = 10µA	
		BC848A/B/C		30					
		BC846A/B		65				Ic = 10mA	
Collector-Emitter Breakdown	Voltage	BC847A/B/C	BVceo	45		_	V		
(Note 9)		BC848A/B/C		30					
Emitter-Base Breakdown Volt	age	BC846A/B BC847A/B/C	BV <sub>EBO</sub>	6	_	_	V	I <sub>E</sub> = 1μA	
		BC848A/B/C		5					
Collector Cutoff Current			Ісво	_		15	nA	Vcb = 30V	
			1000			5	μΑ	VcB = 30V, T <sub>J</sub> = +150°C	
		BC846A/B				15		V <sub>CE</sub> = 80V	
Collector Emitter Cutoff Curre	nt	BC847A/B/C	Ices	_	_	15	nA	Vce = 50V	
		BC848A/B/C				15		Vce = 30V	
Emitter Base Cutoff Current			IEBO	_	_	100	nA	V <sub>EB</sub> = 5V	
Small Signal Current Gain	-	C847A/BC848A			200				
(Note 9)	BC846B/BC847B/BC848B		hfE	_	330	_	_		
. ,	BC847C/BC848C				600				
	BC846A/BC847A/BC848A BC846B/BC847B/BC848B		h <sub>ie</sub>	_	2.7		kΩ		
Input Impedance (Note 9)					4.5	_		I <sub>C</sub> = 2.0mA, V <sub>CE</sub> = 5V	
		BC847C/BC848C			8.7				
		BC846A/BC847A/BC848A			18		μS	f = 1.0kHz	
Output Admittance (Note 9)		BC846B/BC847B/BC848B		_	30	_			
	BC847C/BC848C				60				
Reverse Voltage Transfer		BC846A/BC847A/BC848A			1.5 x 10 <sup>-4</sup>		_		
Ratio (Note 9)		BC846B/BC847B/BC848B		_	2 x 10 <sup>-4</sup>	_			
,	BC847C/B	BC847C/BC848C			3 x 10 <sup>-4</sup>				
		C847A/BC848A		110	180	220			
DC Current Gain (Note 9)		C847B/BC848B	hFE	200	290	450	_	$I_C = 2.0 \text{mA}, V_{CE} = 5 \text{V}$	
	BC847C/B	BC847C/BC848C		420	520	800			
Collector-Emitter Saturation V	oltage (Note	9)	VCE(sat)	_	90	250	mV	$I_C = 10mA, I_B = 0.5mA$	
			- 02(out)			600		$I_C = 100 \text{mA}, I_B = 5.0 \text{mA}$	
Base-Emitter Turn-On Voltage	e (Note 9)		V <sub>BE(on)</sub>	580	660	700	mV	Ic = 2mA, VcE = 5V	
			(***)	_	_	770		$I_C = 10$ mA, $V_{CE} = 5$ V	
Base-Emitter Saturation Voltage (Note 9)		V <sub>BE(sat)</sub>	_	700	_	mV	$I_C = 10mA, I_B = 0.5mA$		
			, ,		900			$I_C = 100 \text{mA}, I_B = 5 \text{mA}$	
Output Capacitance			Cobo	_	3		pF	V <sub>CB</sub> = 10V, f = 1.0MHz	
Transition Frequency			f <sub>T</sub>	100	300	_	MHz	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA f = 100MHz	
Noise Figure			NF	_	2	10	dB	$V_{CE} = 5V$ , $I_{C} = 200\mu A$ $R_{S} = 2k\Omega$ , $f = 1kHz$ $\Delta f = 200Hz$	

Note: 9. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s$ . Duty cycle  $\leq 2\%$ .



# Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

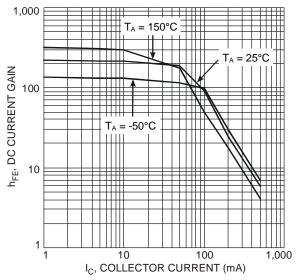


Figure 5. Typical DC Current Gain vs. Collector Current

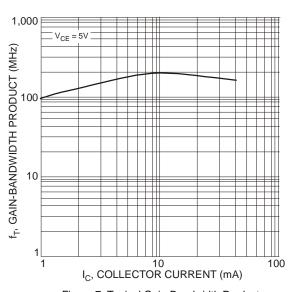


Figure 7. Typical Gain-Bandwidth Product vs. Collector Current

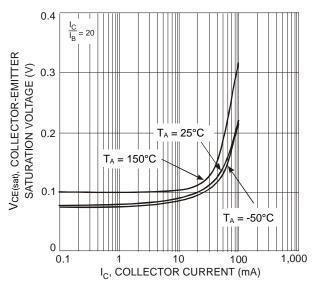


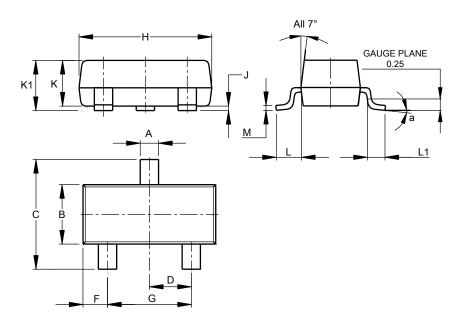
Figure 6. Typical Collector-Emitter Saturation Voltage vs. Collector Current



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

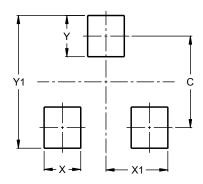


	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All	All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### SOT23



Dimensions	Value (in mm)
C	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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